



Vincotech

A0-VS126TA200SH-L999F74

datasheet

VINcoPACK E3

1200 V / 200 A

Topology features

- Inverter
- Kelvin Emitter for improved switching performance
- Tandem inverter diode
- Temperature sensor

Component features

- Easy paralleling
- High speed switching
- Low switching losses

Housing features

- Base isolation: IMB
- SoLid Cover Technology
- Standard mid-power industry package
- Available with press-fit and solder-pin
- Tin plated solder pin terminals

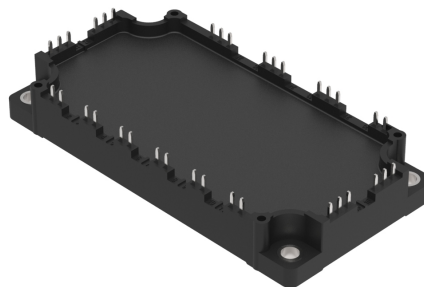
Target applications

- Industrial Drives

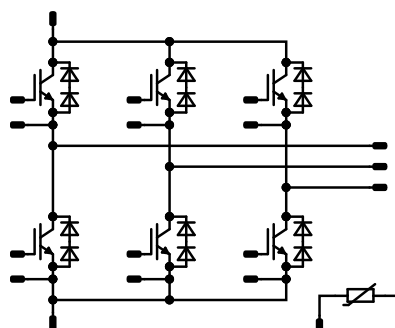
Types

- A0-VS126TA200SH-L999F74

VINco E3 17 mm housing



Schematic





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Maximum Ratings

$T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	208	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	600	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	517	W
Gate-emitter voltage	V_{GES}		±20	V
Short circuit ratings	t_{SC}	$V_{GE} = 15\text{ V}$, $V_{CC} = 800\text{ V}$ $T_j = 150\text{ °C}$	10	µs
Maximum junction temperature	T_{jmax}		175	°C

Inverter Diode

Peak repetitive reverse voltage	V_{RRM}		1300	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	109	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	300	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	313	W
Maximum junction temperature	T_{jmax}		175	°C

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	°C
Operation temperature under switching condition	T_{jop}		-40...+($T_{jmax} - 25$)	°C

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage* $t_p = 2\text{ s}$	6000	V
Isolation voltage	V_{isol}	AC Voltage $t_p = 1\text{ min}$	2500	V
Creepage distance			>12,7	mm
Clearance			9	mm
Comparative Tracking Index	CTI		≥ 200	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0076	25	5,1	5,8	6,4	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		200	25 125 150	1,78	1,99 2,28 2,37	2,42 ⁽¹⁾	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			2,6	µA
Gate-emitter leakage current	I_{GES}		20	0		25			240	nA
Internal gate resistance	r_g							None		Ω
Input capacitance	C_{ies}	$f = 1 \text{ Mhz}$	0	25		25		12300		pF
Reverse transfer capacitance	C_{res}							690		pF
Gate charge	Q_g		±15		0	25		1600		nC

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,18		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	±15	600	200	25 125 150		80,64 81,6 82,24		ns
Rise time	t_r					25 125 150		24,64 27,52 28,16		ns
Turn-off delay time	$t_{d(off)}$					25 125 150		156,16 218,88 239,04		ns
Fall time	t_f					25 125 150		32,99 73,85 86,27		ns
Turn-on energy (per pulse)	E_{on}					25 125 150		3,69 5,69 6,18		mWs
Turn-off energy (per pulse)	E_{off}					25 125 150		7,6 13,75 15,74		mWs



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	

Inverter Diode

Static

Forward voltage	V_F				45	25 125 150	2,06	2,36 2,12 3,32	2,64 ⁽¹⁾	V
Reverse leakage current	I_R	$V_i = 1300$ V				25			1,8	μA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						0,3		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt=7186$ A/μs $di/dt=6822$ A/μs $di/dt=6809$ A/μs	± 15	600	200	25 125 150		111,02 144,05 153,64		A
Reverse recovery time	t_{rr}					25 125 150		155,23 237,96 264,04		ns
Recovered charge	Q_r					25 125 150		5,37 11,29 13,23		μC
Reverse recovered energy	E_{rec}					25 125 150		2,38 5,04 5,91		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		5086 3885 3862		A/μs



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	

Thermistor

Static

Rated resistance	R					25		5		kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 493 \Omega$				100	-5		5	%
Power dissipation	P							245		mW
Power dissipation constant	d					25		1,4		mW/K
B-value	$B_{(25/50)}$	Tol. $\pm 2 \%$						3375		K
B-value	$B_{(25/100)}$	Tol. $\pm 2 \%$						3437		K
Vincotech Thermistor Reference									K	

⁽¹⁾ Value at chip level

⁽²⁾ Only valid with pre-applied Vincotech thermal interface material.



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Inverter Switch Characteristics

figure 1. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

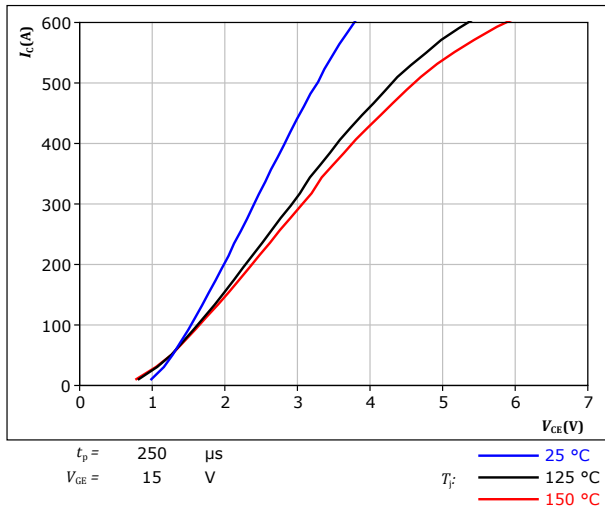


figure 2. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

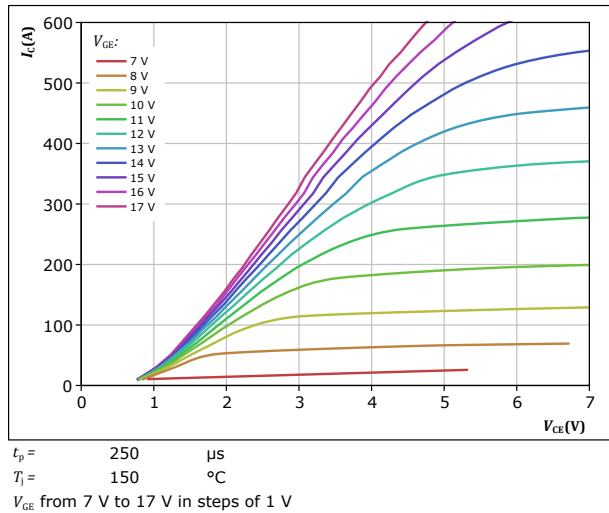


figure 3. IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

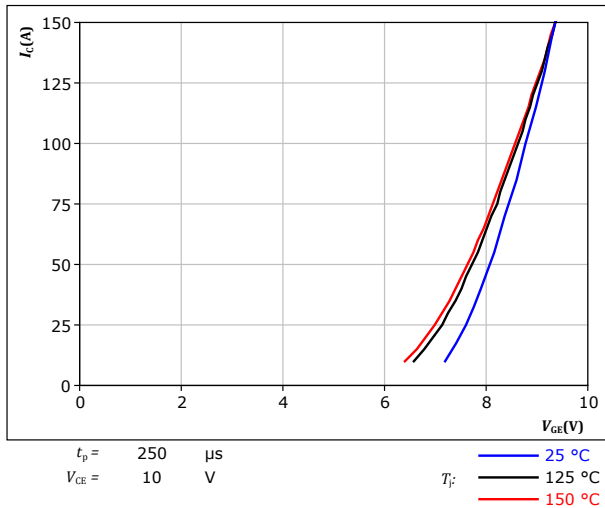
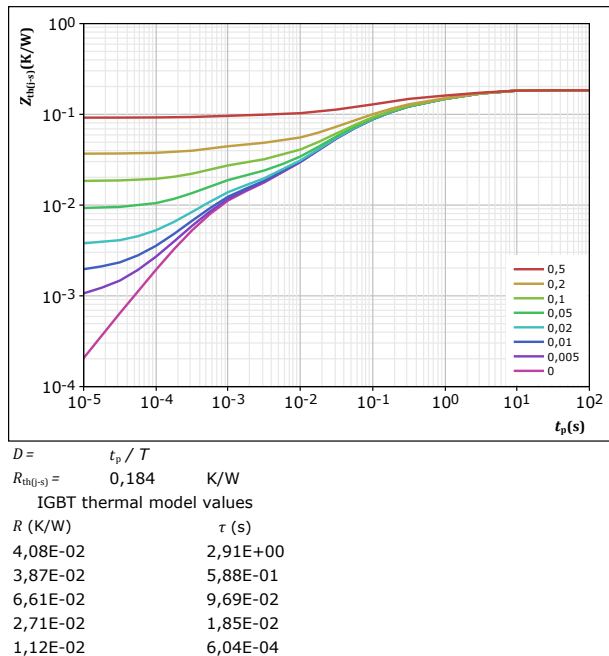


figure 4. IGBT

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$





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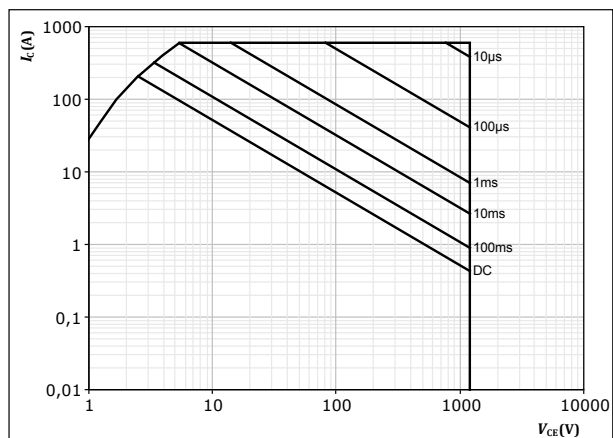
Inverter Switch Characteristics

figure 5.

IGBT

Safe operating area

$I_C = f(V_{CE})$



$D = \text{single pulse}$

$T_s = 80 \text{ } ^\circ\text{C}$
 $V_{GE} = 15 \text{ V}$
 $T_j = T_{jmax}$



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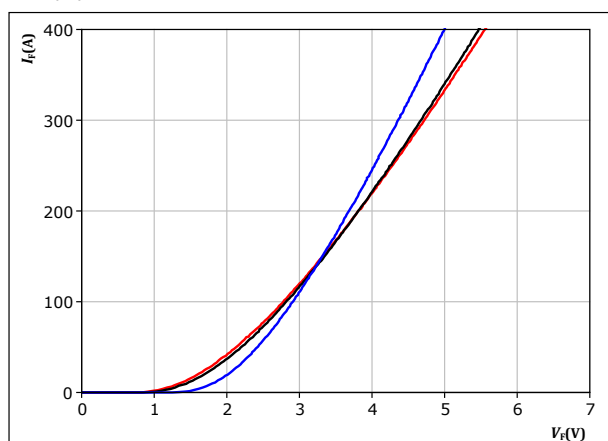
Inverter Diode Characteristics

figure 6.

FWD

Typical forward characteristics

$$I_F = f(V_F)$$



$t_p = 250 \mu s$

T_j :

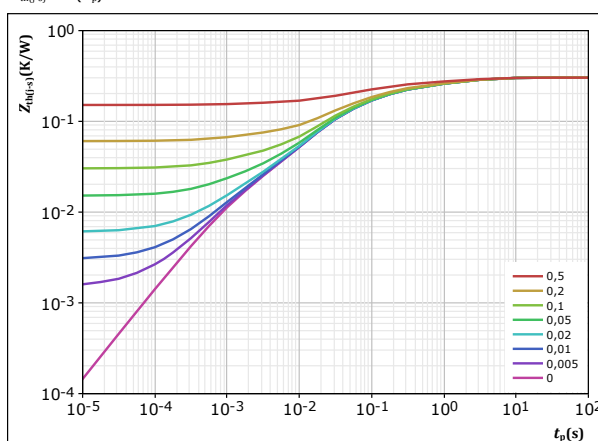
- 25 °C
- 125 °C
- 150 °C

figure 7.

FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$

$R_{th(j-s)} = 0,303 \text{ K/W}$

FWD thermal model values

$R \text{ (K/W)}$	$\tau \text{ (s)}$
3,66E-02	3,45E+00
5,62E-02	7,71E-01
1,04E-01	1,24E-01
9,43E-02	2,46E-02
1,17E-02	1,19E-03



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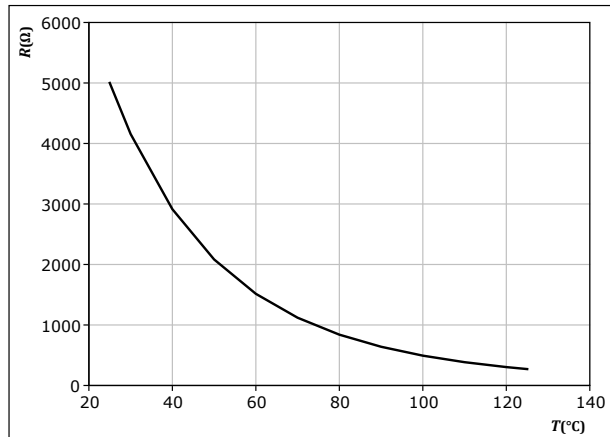
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Thermistor Characteristics

figure 8. Thermistor

Typical NTC characteristic as function of temperature

$$R_T = f(T)$$





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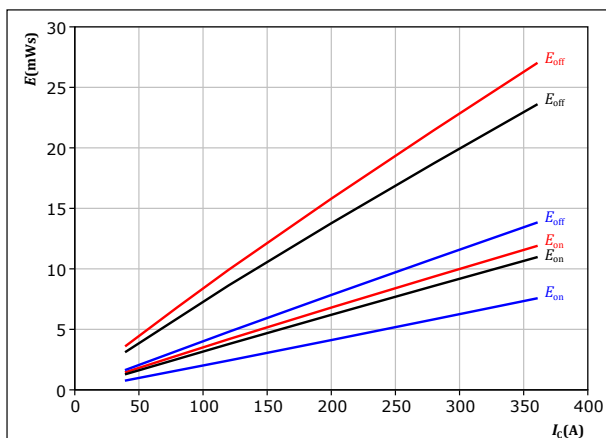
Inverter Switching Characteristics

figure 9.

IGBT

Typical switching energy losses as a function of collector current

$$E = f(I_C)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \text{ } \Omega$
 $R_{goff} = 2 \text{ } \Omega$

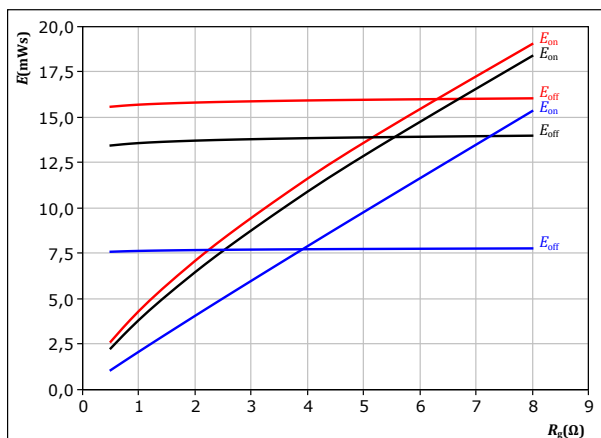
T_j :
— 25 °C
— 125 °C
— 150 °C

figure 10.

IGBT

Typical switching energy losses as a function of IGBT turn on gate resistor

$$E = f(R_g)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 200 \text{ A}$

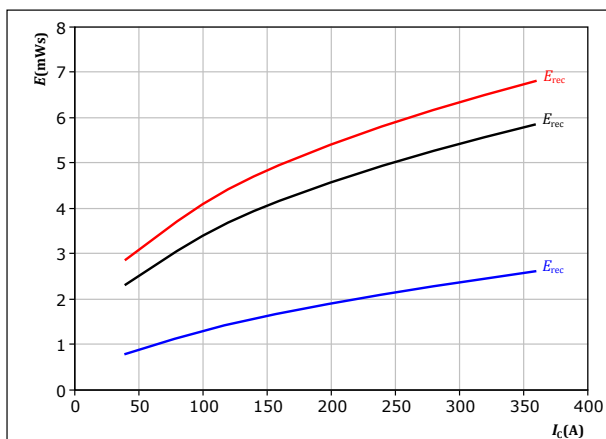
T_j :
— 25 °C
— 125 °C
— 150 °C

figure 11.

FWD

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_C)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \text{ } \Omega$

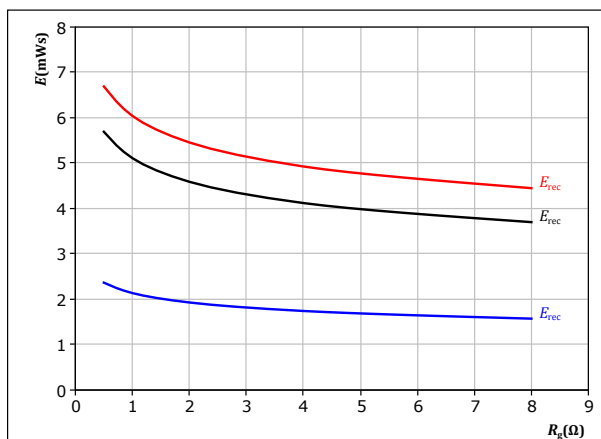
T_j :
— 25 °C
— 125 °C
— 150 °C

figure 12.

FWD

Typical reverse recovered energy loss as a function of IGBT turn on gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 200 \text{ A}$

T_j :
— 25 °C
— 125 °C
— 150 °C



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Inverter Switching Characteristics

figure 13.

IGBT

Typical switching times as a function of collector current
 $t = f(I_C)$

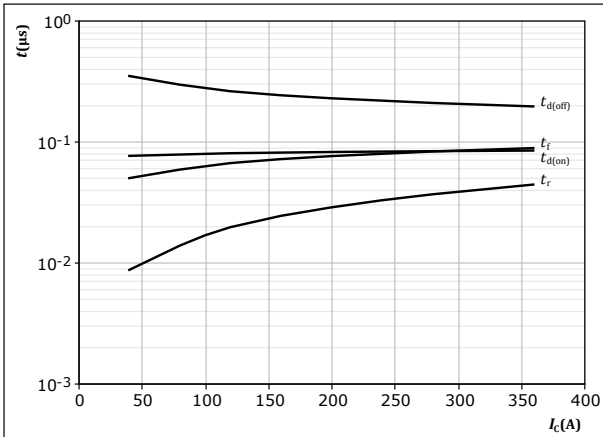


figure 14.

IGBT

Typical switching times as a function of IGBT turn on gate resistor
 $t = f(R_g)$

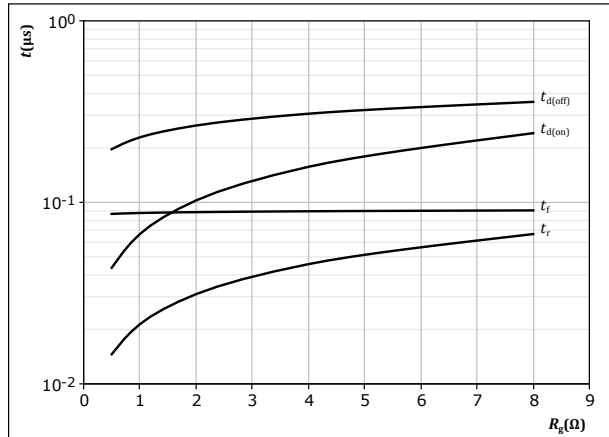


figure 15.

FWD

Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_C)$

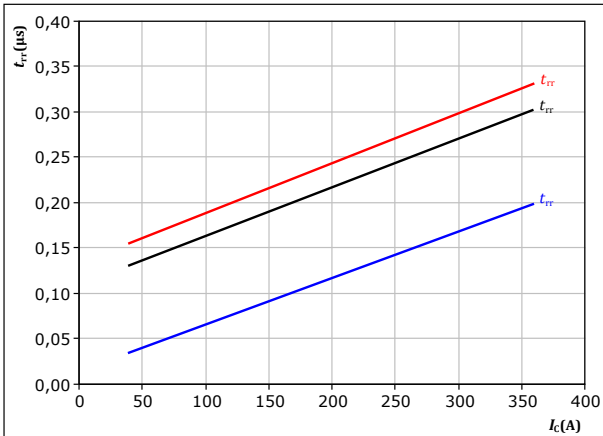
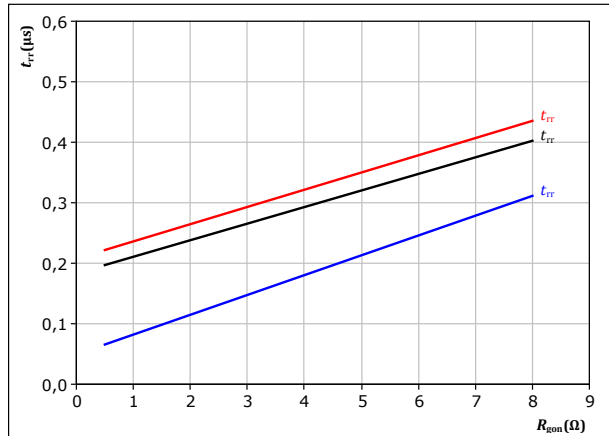


figure 16.

FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor
 $t_{rr} = f(R_{gon})$





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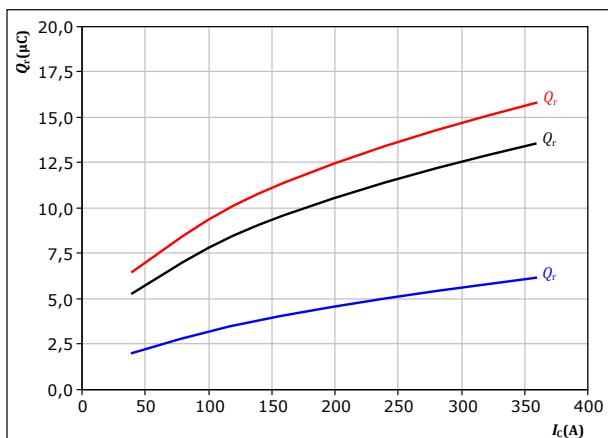
Inverter Switching Characteristics

figure 17.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 2$ Ω

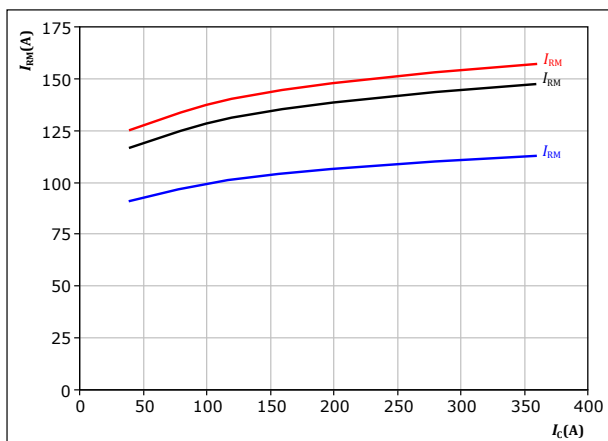
T_j : 25 °C
125 °C
150 °C

figure 19.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 2$ Ω

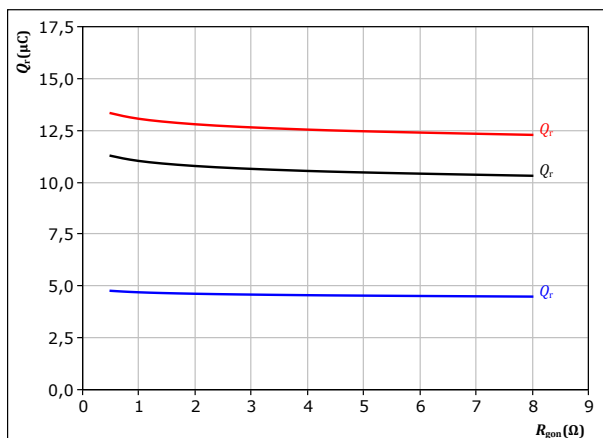
T_j : 25 °C
125 °C
150 °C

figure 18.

FWD

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_c = 200$ A

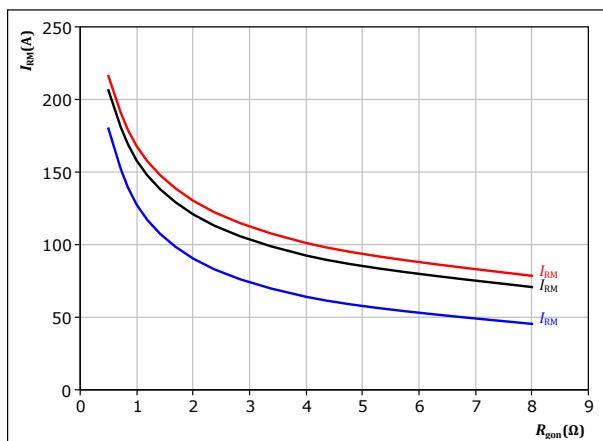
T_j : 25 °C
125 °C
150 °C

figure 20.

FWD

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_c = 200$ A

T_j : 25 °C
125 °C
150 °C



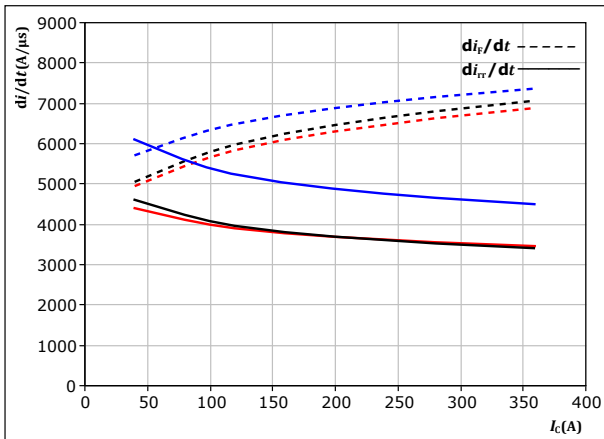
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Inverter Switching Characteristics

figure 21. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_r/dt = f(I_C)$



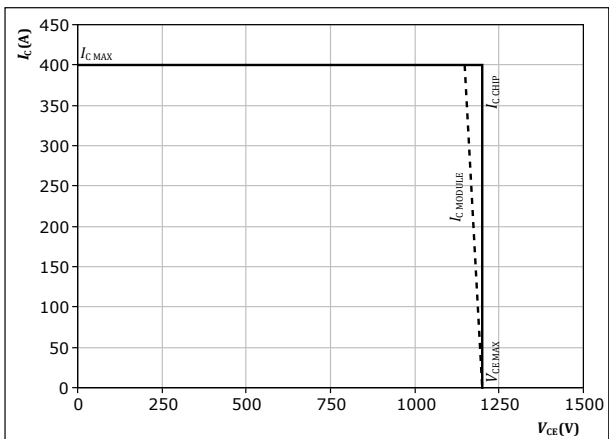
With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 2$ Ω
 $T_j = 25^\circ\text{C}$
 $T_j = 125^\circ\text{C}$
 $T_j = 150^\circ\text{C}$

figure 22. FWD

Reverse bias safe operating area

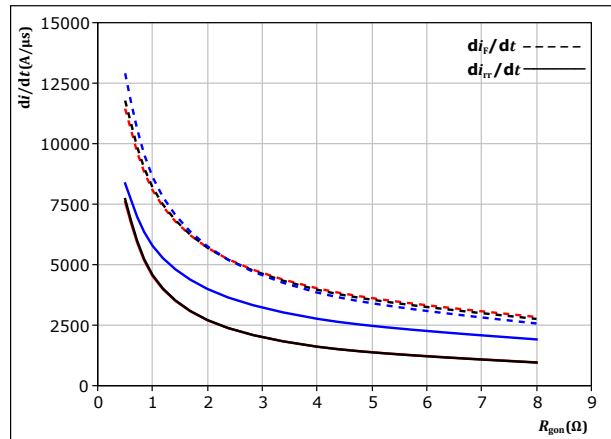
$I_C = f(V_{CE})$



At $T_j = 150^\circ\text{C}$
 $R_{gon} = 2$ Ω
 $R_{goff} = 2$ Ω

figure 23. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_r/dt = f(R_{gon})$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 200$ A
 $T_j = 25^\circ\text{C}$
 $T_j = 125^\circ\text{C}$
 $T_j = 150^\circ\text{C}$



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Inverter Switching Definitions

figure 24. IGBT

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})

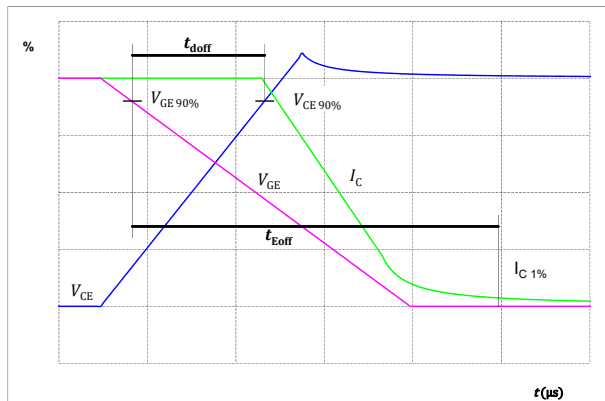


figure 25. IGBT

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

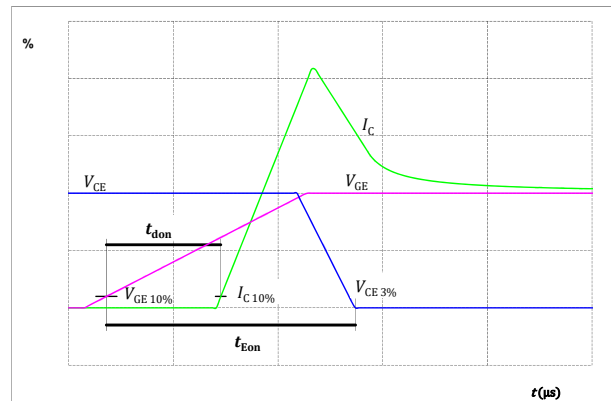


figure 26. IGBT

Turn-off Switching Waveforms & definition of t_f

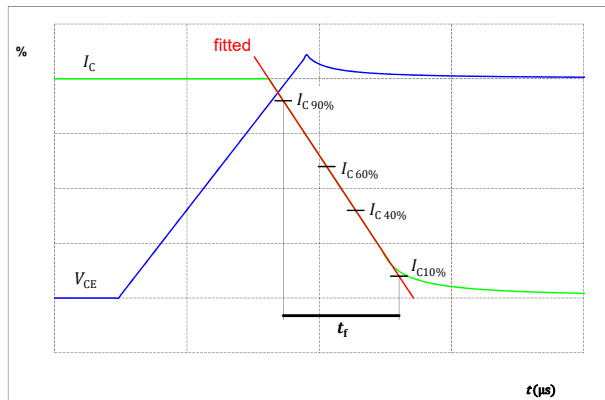
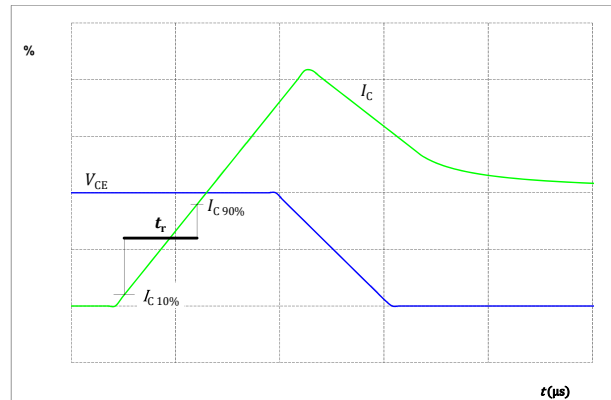


figure 27. IGBT

Turn-on Switching Waveforms & definition of t_r





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Inverter Switching Definitions

figure 28.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

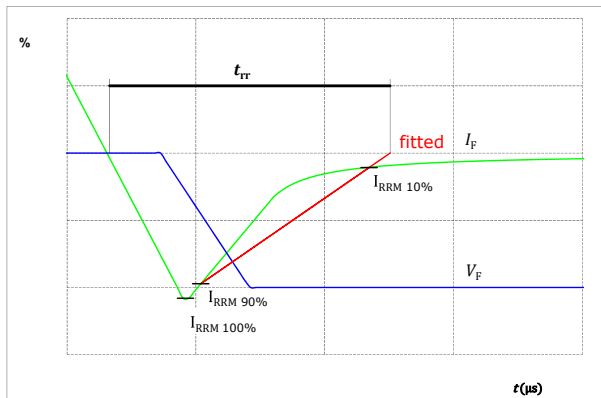
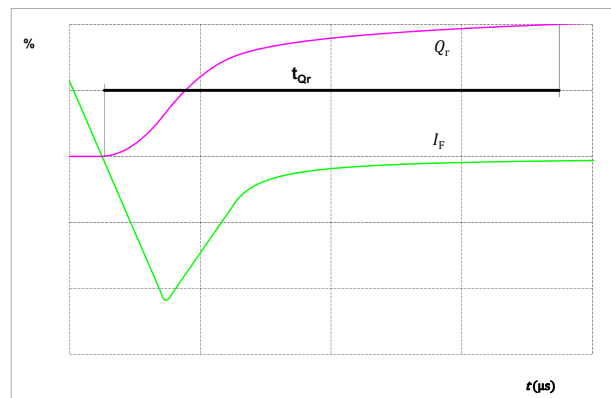


figure 29.

FWD

Turn-on Switching Waveforms & definition of t_{Qr} (t_{Qr} = integrating time for Q_r)





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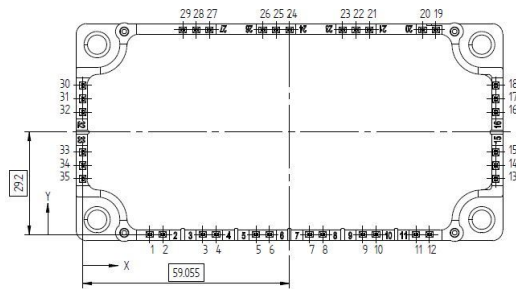
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Ordering Code	
Version	Ordering Code
Without thermal paste	A0-VS126TA200SH-L999F74
With thermal paste (3,4 W/mK, PSX-P7)	A0-VS126TA200SH-L999F74-/3/

Marking						
	Text	Name NN-NNNNNNNNNNNNNNNN- TTTTTIVV	VIN VIN	Date code WWYY	Lot LLLLL	Serial SSSS
	Datamatrix	Type&Ver TTTTTIVV	Lot number LLLLL	Serial SSSS	Date code WWYY	

Outline			
Pin table [mm]			
Pin	X	Y	Function
1	19,05	0	G12
2	22,86	0	S12
3	34,29	0	G11
4	38,1	0	S11
5	49,53	0	G14
6	53,34	0	S14
7	64,77	0	G13
8	68,58	0	S13
9	80,01	0	G16
10	83,82	0	S16
11	95,25	0	G15
12	99,06	0	S15
13	118,11	15,865	DC-123
14	118,11	19,675	DC-123
15	118,11	23,485	DC-123
16	118,11	34,915	DC+123
17	118,11	38,725	DC+123
18	118,11	42,535	DC+123
19	100,965	58,4	Therm1
20	97,155	58,4	Therm2
21	81,915	58,4	Ph3
22	78,105	58,4	Ph3
23	74,295	58,4	Ph3
24	59,055	58,4	Ph2
25	55,245	58,4	Ph2
26	51,435	58,4	Ph2
27	36,195	58,4	Ph1
28	32,385	58,4	Ph1
29	28,575	58,4	Ph1
30	0	42,535	DC+123
31	0	38,725	DC+123
32	0	34,915	DC+123
33	0	23,485	DC-123
34	0	19,675	DC-123
35	0	15,865	DC-123

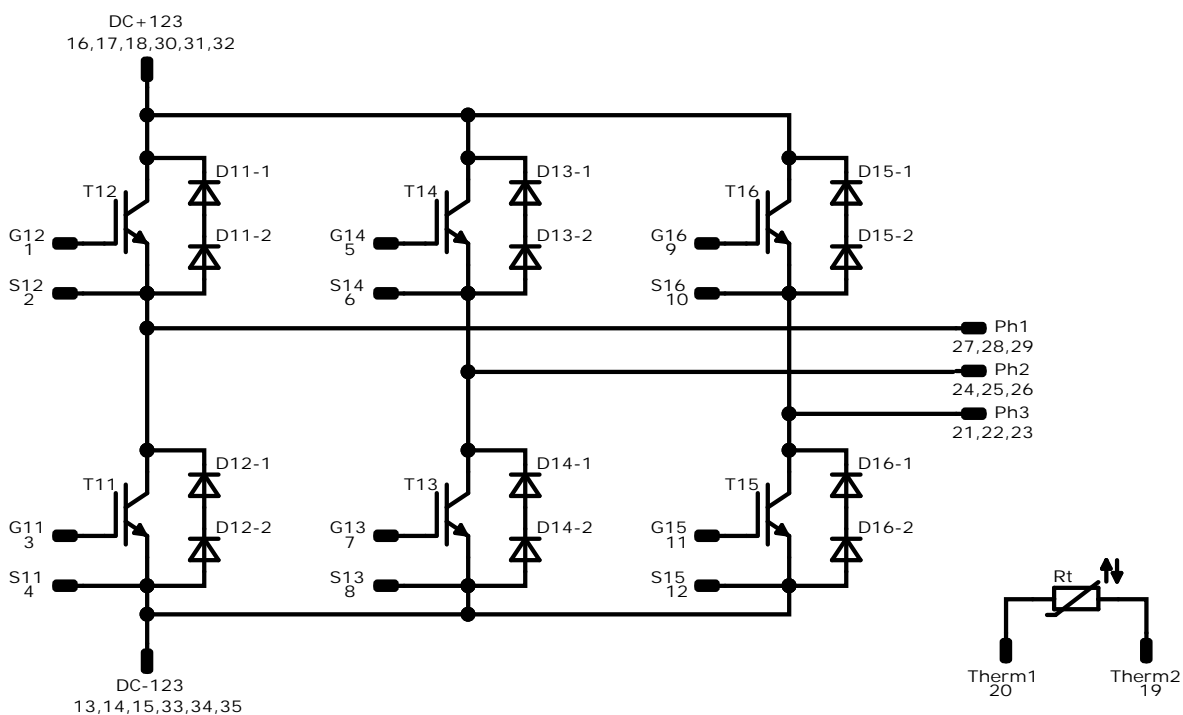




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Pinout



Identification

ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	1200 V	200 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1300 V	150 A	Inverter Diode	
Rt	NTC			Thermistor	



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Packaging instruction				
Standard packaging quantity (SPQ) 24	>SPQ	Standard	<SPQ	Sample

Handling instruction
Handling instructions for VINco E3 packages see vincotech.com website.

Package data
Package data for VINco E3 packages see vincotech.com website.

Vincotech thermistor reference
See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.



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A0-VS126TA200SH-L999F74-D2-14	6 Apr. 2022	Add UL recognition information	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.